

1N5550US THRU 1N5554US Surface Mount Hermetically Sealed Standard Recovery Rectifier Diode

POWER DISCRETES

Description

Quick reference data

$$V_{R} = 200 - 1000V$$
 $I_{F} = 5.0A$
 $t_{rr} = 2\mu S$
 $V_{F} = 1.0V$

Features

- ◆ Low reverse leakage current
- ◆ Hermetically sealed in fused metal oxide
- ◆ Good thermal shock resistance
- ◆ Low forward voltage drop
- Avalanche capability

These products are qualified to MIL-PRF-19500/420. They can be supplied fully released as JAN, JANTX, JANTXV, and JANS versions.

Absolute Maximum Ratings

Electrical specifications @ $T_{\Delta} = 25^{\circ}$ C unless otherwise specified.

	Symbol	1N5550US	1N5551US	1N5552US	1N5553US	1N5554US	Units
Working Reverse Voltage	V_{RWM}	200	400	600	800	1000	V
Average Forward Current @55 °C in free air, lead length 0.375"	l _{F(AV)}	5.0					Α
Repetitive Surge Current @55 °C in free air, lead length 0.375"	I _{FRM}	25					А
Non-Repetitive Surge Current (tp = 8.3mS @ $V_R \& T_{JMAX}$) (tp = 8.3mS, @ $V_R \& 25 °C$)	I _{FSM}	100 150					Α
Storage Temperature Range	T _{STG}	-65 to +175					°C

Revision: August 22nd, 2011 1 www.micross.com



one source, one solution.

POWER DISCRETES

Electrical Specifications

	Symbol	1N5550US	1N5551US	1N5552US	1N5553US	1N5554US	Units
Average Forward Current (sine wave) - max. $T_A = 55 ^{\circ}\text{C}$ - max. L = 3/8"; $T_L = 55 ^{\circ}\text{C}$	 F(AV) F(AV)			3.0 5.0			А
It for fusing (t = 8.3mS) max	l²t			42			A ² S
Forward Voltage Drop max. @ I _F = 3.0A, T _j = 25 °C	V _F			1.0			V
Reverse Current max. @ V _{RWM} , Tj = 25°C @ V _{RWM} , Tj = 125°C	 			1.0 60			μΑ
Reverse Recovery Time max. 0.5A $I_{\rm F}$ to 1.0A $I_{\rm RM}$ recovers to 0.25A $I_{\rm RM(REC)}$	trr			2.0			μS
Junction Capacitance typ. @ V _R = 5V, f = 1MHz	Cj			92			pF

Thermal Characteristics

	Symbol	1N5550US	1N5551US	1N5552US	1N5553US	1N5554US	Units
R _{ØJEC}	R _{ØJEC} at L= 0 inch	6.5				C/W	

Typical Characteristics

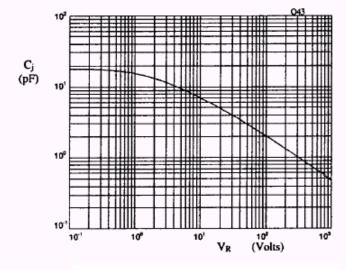


Fig 1. Typical junction capacitance as a function of reverse voltage.

POWER DISCRETES

Typical Characteristics

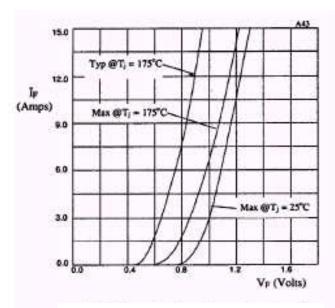


Fig 2. Forward voltage drop as a function of forward current

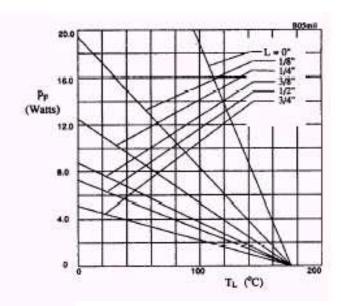


Fig 3. Maximum power versus lead temperature

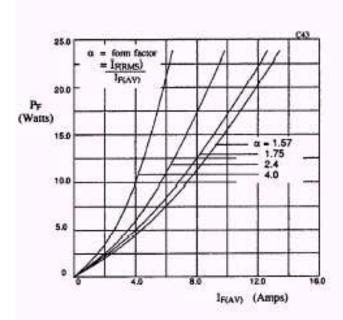


Fig 4. Forward power dissipation as a function of forward current, for sinusoidal operation.

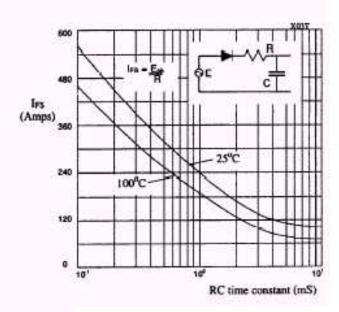


Fig 5. Maximum ratings for capacitive loads.



one source, one solution:

POWER DISCRETES

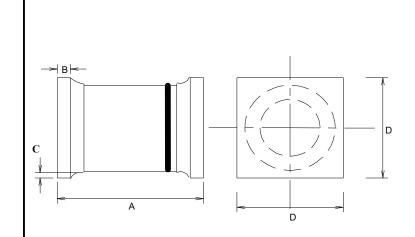
Ordering Information

Part Number	Description
1N5550US 1N5551US 1N5552US 1N5553US 1N5554US	Surface Mount hermetically sealed ⁽¹⁾

Note:

(1) Available in bulk and tape and reel packaging. Please consult factory for quantities.

Outline Drawing



Dimensions								
D.114N	Inc	hes	Millin	Note				
DIM ^N	MIN	MAX	MIN	MAX				
Α	0.2	0.275	5.08	6.99	-			
В	0.019	0.034	0.48	0.86	-			
С	0.003		0.08		-			
D	0.137	0.186	3.48	4.72	-			